PCN Num	ber:	20160504000	504000			PCN Date:		05/06/2016
Title: TPS650 Die Revision Change								
Customer Contact:		PCN Manager		Dept:			Quality Services	
Proposed 1st Ship Date:		08/06/2016	Estimated Samp Availability:	mple			Date provided at sample request.	
Change T	ype:		•					•
Assem	nbly Site	Assembly Pr	Assembly Process			Assembly Materials		
□ Design □	า	Electrical Sp	Electrical Specification			Mechanical Specification		
Test S	ite	Packing/Shi	pping/Labeling			Test P		
	Bump Site	Wafer Bump				Wafer	Bun	np Process
Wafer	Fab Site	☐ Wafer Fab M	<u>laterials</u>			Wafer Fab Process		
		Part number	r change					
		PCN	Details					
Description of Change:								
This notification is to inform of a die revision change to select devices. A design change was performed in order to improve the robustness against Vin dips to correct issues observed at different fall/raise time and durations. The design change does not affect the form fit or function of the device. There will be no accompanying changes to the device specifications. The design changes do not affect the device's guaranteed datasheet specifications or electrical performance. Affected devices are listed in the product affected section of this document. Reason for Change:								
Improved product performance								
Anticipated impact on Form, Fit, Function, Quality or Reliability (positive / negative):								
None								
Changes to product identification resulting from this PCN:								
Die Rev designator will change as shown in the table and sample label below: Current Die Rev [2P] B C								

Sample product shipping label (not actual product label)







Product Affected:

				_
TPS63050YFFR	TDC63050VEET	TDC63051VEED	TDC63051VEET	
1P3030301FFK	175030301771	152020211LLK	15202021111	

Qualification Report

TPS63050YFF and TPS63051YFF Die Rev C

Approve Date 26-Apr-2016

Product Attributes

Attributes	Qual Device: TPS63050YFF	Qual Device: TPS63051YFF	QBS Product Reference: TPS63050RMW	QBS Product Reference: TPS63050YFF	QBS Process Reference: TPS65830YFF	QBS Package Reference: TPS63010YFF
Assembly Site	CLARK AT	CLARK AT	CLARK AT	CLARK AT	CLARK AT	CLARK AT
Package Family	WCSP	WCSP	HotRod	WCSP	WCSP	WCSP
Wafer Fab Supplier	RFAB/CLARK-BUMP	RFAB	RFAB	RFAB/CLARK-BUMP	RFAB	MIHO8
Wafer Process	LBC7X	LBC7	LBC7	LBC7x	LBC7	LBC7

Qualification Results

Data Displayed as: Number of lots / Total sample size / Total failed

Туре	Test Name / Condition	Duration	Qual Device: TPS63050YFF	Qual Device: TPS63051YFF	QBS Product Reference: TPS63050RMW	QBS Product Reference: TPS63050YFF	QBS Process Reference: TPS65830YFF	QBS Package Reference: TPS63010YFF
ED	Electrical Characterization	Per Datasheet Parameters	Pass	-	Pass	Pass	-	Pass
HAST	Biased HAST 130C,85%RH	96 Hours		-	-	-	-	3/231/0
HBM	ESD - HBM	1750 V	-	-	-	1/3/0	-	-
CDM	ESD - CDM	1000 V	-	-	1/3/0	1/3/0	-	-
HTSL	High Temp. StorageBake, 170C	420 Hours	-	-	-	-	-	3/231/0
HTOL	Life Test, 150C	300 Hours	-	-	-	-	3/231/0	3/231/0
LU	Latch-up	(per JESD78)	1/6/0	-	1/6/0	1/6/0	3/18/0	-
YLD	MPY and Bin Summary		Pass	Pass	-	-	-	-
PD	Physical Dimensions			-	3/90/0	-	-	3/15/0
SBS	Solder Ball Shear		-	-	-	-	-	3/150/0
TC	Temperature Cycle, -55/125C	700 Cycles	-	-	1/77/0	-	3/229/0	3/231/0
TC	Temperature Cycle, -65/150C	500/-65/+150	-	-	1/77/0	-	-	-
UHAST	Unbiased HAST, 130C/85%RH	96 Hours	-	-	-	-	3/228/0	3/231/0

Green/Pb-free Status: Qualified Pb-Free (SMT) and Green

For questions regarding this notice, e-mails can be sent to the regional contacts shown below, or you can contact your local Field Sales Representative.

Location	E-Mail
USA	PCNAmericasContact@list.ti.com
Europe	PCNEuropeContact@list.ti.com
Asia Pacific	PCNAsiaContact@list.ti.com
Japan	PCNJapanContact@list.ti.com

⁻ QBS: Qual by Similarity - Qual Devices qualified at LEVEL1-260C: TPS63051YFF, TPS63050YFF

⁻ Preconditioning was performed for Autoclave, Unbiased HAST, THB/Bliased HAST, Temperature Cycle, Thermal Shock, and HTSL, as applicable

- The following are equivalent HTGL options based on an activation energy of 0.7eV: 125C/1k Hours, 140C/480 Hours, 150C/300 Hours, and 155C/240 Hours

- The following are equivalent HTSL options based on an activation energy of 0.7eV: 150C/1k Hours, and 170C/420 Hours

- The following are equivalent HTBL options based on an activation energy of 0.7eV: 150C/1k Hours, and 170C/420 Hours

- The following are equivalent HTBL options based on an activation energy of 0.7eV: 150C/1k Hours, and 170C/420 Hours

- The following are equivalent HTBL options based on an activation energy of 0.7eV: 150C/1k Hours, and 170C/420 Hours

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- The following are equivalent HTBL options based on an activation energy of 0.7eV: 150C/1k Hours, and 170C/420 Hours

- The following are equivalent HTBL options based on an activation energy of 0.7eV: 150C/1